# NSN 5962-01-352-1881

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AeroBase Group

View Online at https://aerobasegroup.com/nsn/5962-01-352-1881

## **Overall Height:**

0.400 inches

#### **Body Length:**

1.060 inches

### Body Width:

Between 0.220 inches and 0.310 inches

#### **Body Height:**

Between 0.130 inches and 0.185 inches

#### **Maximum Power Dissipation Rating:**

1.0 watts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **Features Provided:**

Hermetically sealed and burn in and monolithic and positive outputs

#### Inclosure Material:

Ceramic

#### Inclosure Configuration:

Dual-in-line

### Output Logic Form:

Complementary-metal oxide-semiconductor logic

#### Input Circuit Pattern:

16 input

#### Case Outline Source And Designator:

D-8 mil-m-38510

#### **Current Rating Per Characteristic:**

70.00 milliamperes reverse current, dc absolute

#### **Terminal Surface Treatment:**

Solder

#### **Product Name:**

And-or invert logic array

#### Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

#### **Capitance Rating Per Characteristic:**

7.00 input picofarads and 7.00 output picofarads

#### **Time Rating Per Chacteristic:**

20.00 nanoseconds delay

#### Memory Device Type:

Pal

#### **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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## Terminal Type And Quantity:

20 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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### Demilitarization:

Yes - demil/mli

Fiig:

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